

# Silicon PIN Photodiode with Daylight Blocking Filter

## Version 1.4

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### BP 104 F



#### Features:

- Especially suitable for applications of 950 nm
- Short switching time (typ. 20 ns)
- DIL plastic package with high packing density
- The product qualification test plan is based on the guidelines of AEC-Q101-REV-C, Stress Test Qualification for Automotive Grade Discrete Semiconductors.

#### Applications

- Photointerrupters
- Remote control

#### Ordering Information

Type:	Photocurrent $I_P$ [ $\mu$ A] $\lambda = 950 \text{ nm}$ , $E_e = 1 \text{ mW/cm}^2$ , $V_R = 5 \text{ V}$	Ordering Code
BP 104 F	34 ( $\geq 25$ )	Q62702P0084

**Maximum Ratings** ( $T_A = 25\text{ °C}$ )

Parameter	Symbol	Values	Unit
Operating and storage temperature range	$T_{op}; T_{stg}$	-40 ... 100	°C
Reverse voltage	$V_R$	20	V
Total Power dissipation	$P_{tot}$	150	mW
ESD withstand voltage (acc. to ANSI/ ESDA/ JEDEC JS-001 - HBM)	$V_{ESD}$	2000	V

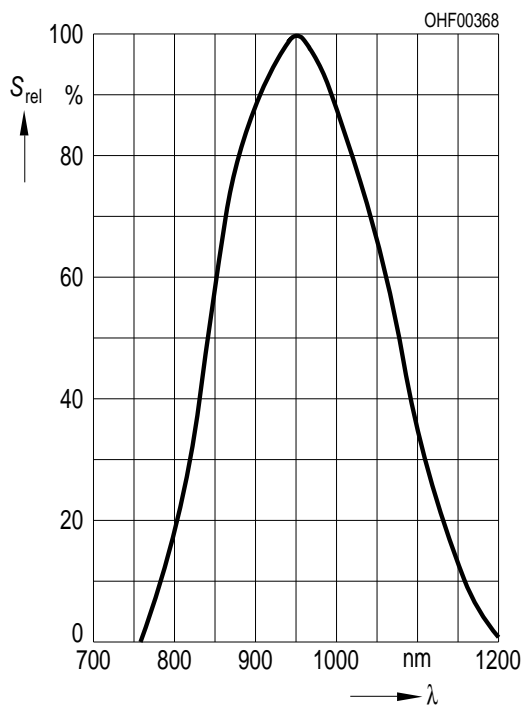
**Characteristics** ( $T_A = 25\text{ °C}$ )

Parameter	Symbol	Values	Unit
Photocurrent ( $V_R = 5\text{ V}$ , $E_e = 1\text{ mW/cm}^2$ , $\lambda = 950\text{ nm}$ )	(typ (min)) $I_p$	34 ( $\geq 25$ )	$\mu\text{A}$
Wavelength of max. sensitivity	(typ) $\lambda_{S\max}$	950	nm
Spectral range of sensitivity	(typ) $\lambda_{10\%}$	(typ) 800 ... 1100	nm
Radiant sensitive area	(typ) $A$	4.84	$\text{mm}^2$
Dimensions of radiant sensitive area	(typ) $L \times W$	2.2 x 2.2	mm x mm
Half angle	(typ) $\varphi$	$\pm 60$	°
Dark current ( $V_R = 10\text{ V}$ )	(typ (max)) $I_R$	2 ( $\leq 30$ )	nA
Spectral sensitivity of the chip ( $\lambda = 950\text{ nm}$ )	(typ) $S_{\lambda\text{ typ}}$	0.7	A / W
Quantum yield of the chip ( $\lambda = 950\text{ nm}$ )	(typ) $\eta$	0.91	Electrons / Photon
Open-circuit voltage ( $E_e = 0.5\text{ mW/cm}^2$ , $\lambda = 950\text{ nm}$ )	(typ (min)) $V_O$	330 ( $\geq 250$ )	mV
Short-circuit current ( $E_e = 0.5\text{ mW/cm}^2$ , $\lambda = 950\text{ nm}$ )	(typ) $I_{SC}$	17	$\mu\text{A}$
Rise and fall time ( $V_R = 5\text{ V}$ , $R_L = 50\ \Omega$ , $\lambda = 850\text{ nm}$ , $I_p = 800\ \mu\text{A}$ )	(typ) $t_r, t_f$	0.02	$\mu\text{s}$
Forward voltage ( $I_F = 100\text{mA}$ , $E_e = 0$ )	(typ) $V_F$	1.3	V
Capacitance ( $V_R = 0\text{ V}$ , $f = 1\text{ MHz}$ , $E = 0$ )	(typ) $C_0$	48	pF
Temperature coefficient of $V_O$	(typ) $TC_V$	-2.6	mV / K

Parameter		Symbol	Values	Unit
Temperature coefficient of $I_{SC}$ ( $\lambda = 950 \text{ nm}$ )	(typ)	$TC_1$	0.18	% / K
Noise equivalent power ( $V_R = 10 \text{ V}$ , $\lambda = 950 \text{ nm}$ )	(typ)	NEP	0.036	$\text{pW} / \text{Hz}^{1/2}$
Detection limit	(typ)	$D^*$	$6.1 \times 10^{12}$	$\text{cm} \times \text{Hz}^{1/2} / \text{W}$

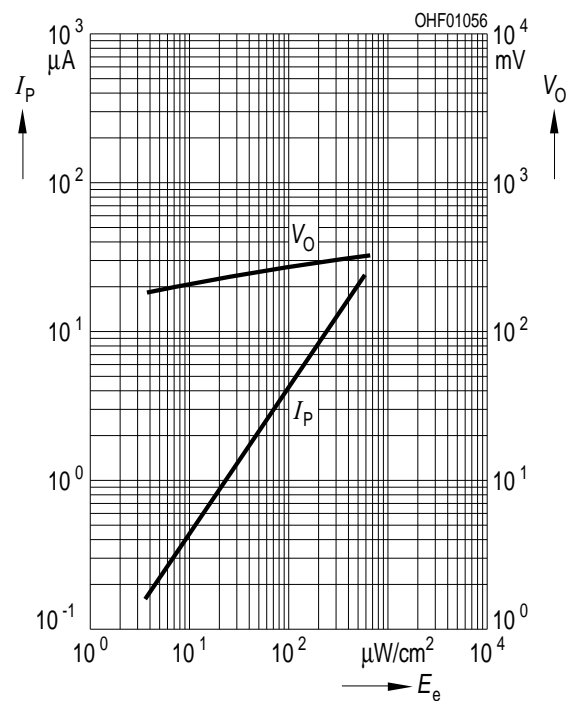
### Relative Spectral Sensitivity <sup>1) page 8</sup>

$$S_{rel} = f(\lambda)$$



### Photocurrent / Open-Circuit Voltage <sup>1) page 8</sup>

$$I_P (V_R = 5 \text{ V}) / V_O = f(E_e)$$



**Power Consumption**

$P_{tot} = f(T_A)$



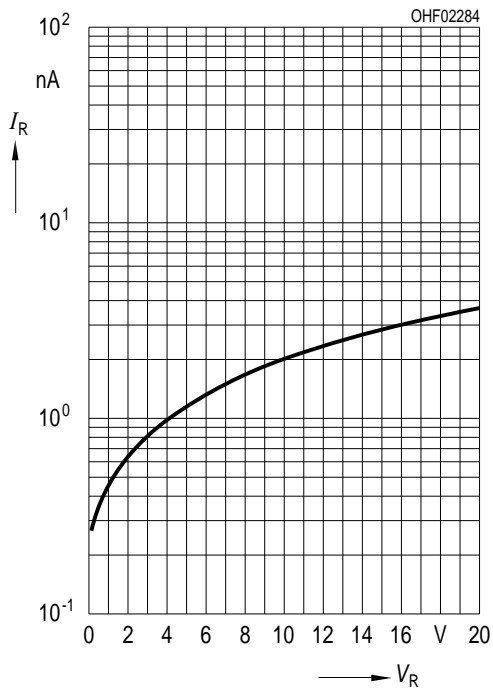
**Dark Current** <sup>1) page 8</sup>

$I_R = f(V_R), E = 0$



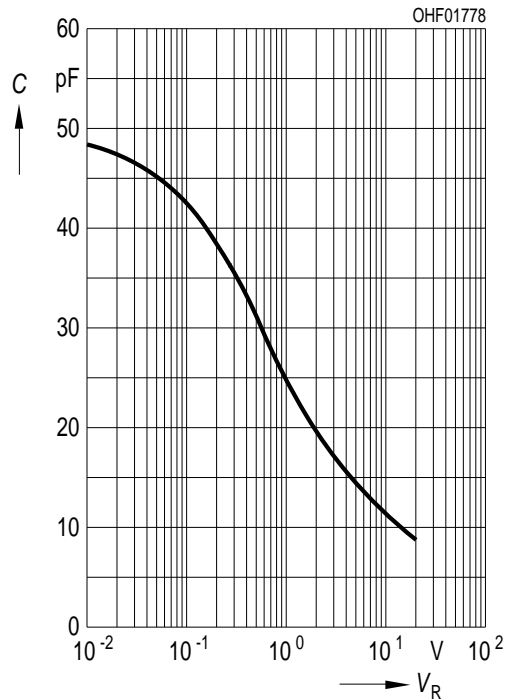
**Dark Current** <sup>1) page 8</sup>

$I_R = f(V_R), E = 0$



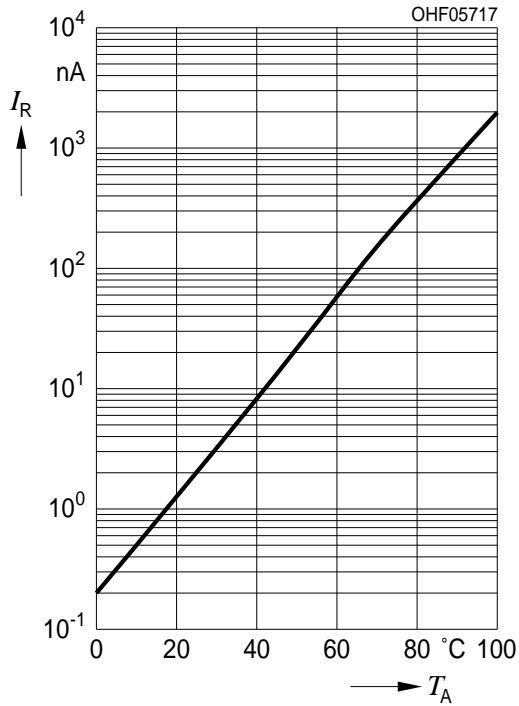
**Capacitance** <sup>1) page 8</sup>

$C = f(V_R), f = 1 \text{ MHz}, E = 0$



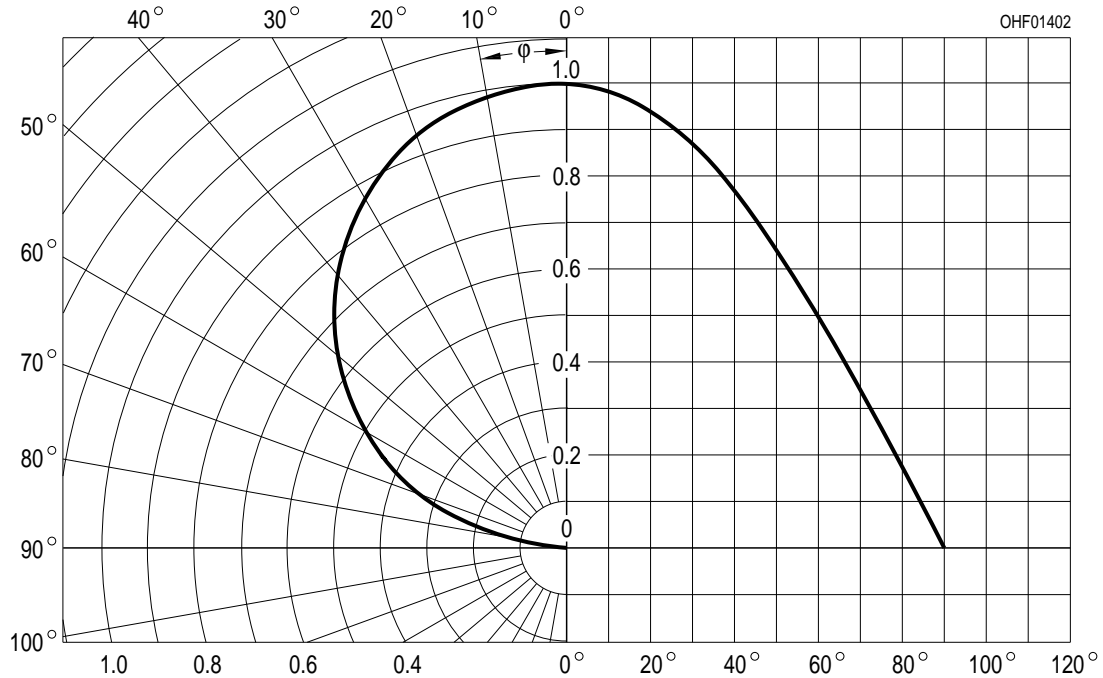
**Dark Current** <sup>1) page 8</sup>

$I_R = f(T_A), V_R = 10\text{ V}, E = 0$

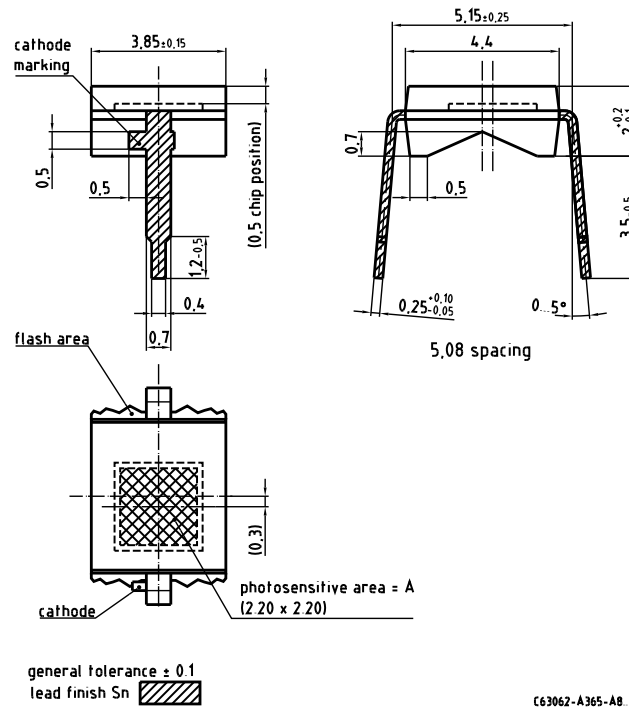


**Directional Characteristics** <sup>1) page 8</sup>

$S_{rel} = f(\phi)$



## Package Outline



*Dimensions in mm (inch).*

**Package**

DIL, Epoxy

**Approximate Weight:**

72 mg

**TTW Soldering**

IEC-61760-1 TTW

**Disclaimer**

Language english will prevail in case of any discrepancies or deviations between the two language wordings.

**Attention please!**

The information describes the type of component and shall not be considered as assured characteristics.

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\*\*) Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health and the life of the user may be endangered.

**Glossary**

- <sup>1)</sup> **Typical Values:** Due to the special conditions of the manufacturing processes of LED, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.



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